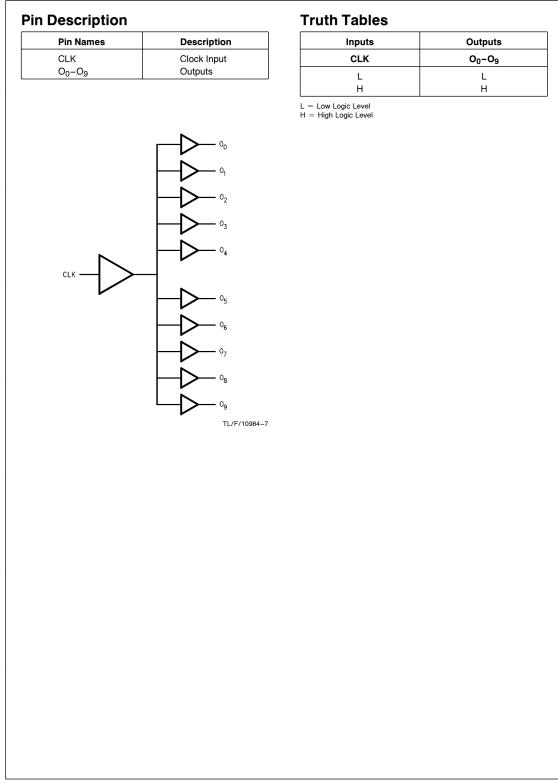


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## Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	(V <sub>CC</sub> )			7.0V		
Input Voltage (	√ <sub>I</sub> )			7.0V		
Operating Tem	perature	64 Grade	e −40°C	$-40^{\circ}$ C to $+85^{\circ}$ C		
		74 Grade	)°0	C to +70°C		
Storage Tempe	Storage Temperature Range -65°C to +		to +150°C			
Typical $\theta_{JA}$	М	Ν	V			
0 LFM	89	71	64	°C/W		
225 LFM	71	57	52	°C/W		
500 LFM	63	48	45	°C/W		

## Recommended Operating Conditions

Supply Voltage (V <sub>CC</sub> )	4.5V to 5.5V						
Input Rise and Fall Times	0.6						
(0.8V to 2.0V)	9.6 ns max						
Free Air Operating Temperature 64 (T <sub>A</sub> )	$-40^{\circ}$ C to $+85^{\circ}$ C						
Free Air Operating Temperature 74 (T <sub>A</sub> )	$-0^{\circ}C$ to $+70^{\circ}C$						
NOTE: The Absolute Maximum Ratings are those values							
beyond which the safety of the device cannot be guaran-							
teed. The device should not be operated a	at these limits. The						
parametric values defined in the DC and	AC Electrical Char-						
acteristics tables are not quaranteed at							
mum ratings. The Recommended Operation							
0	0						
define the conditions for actual device of	peralion.						

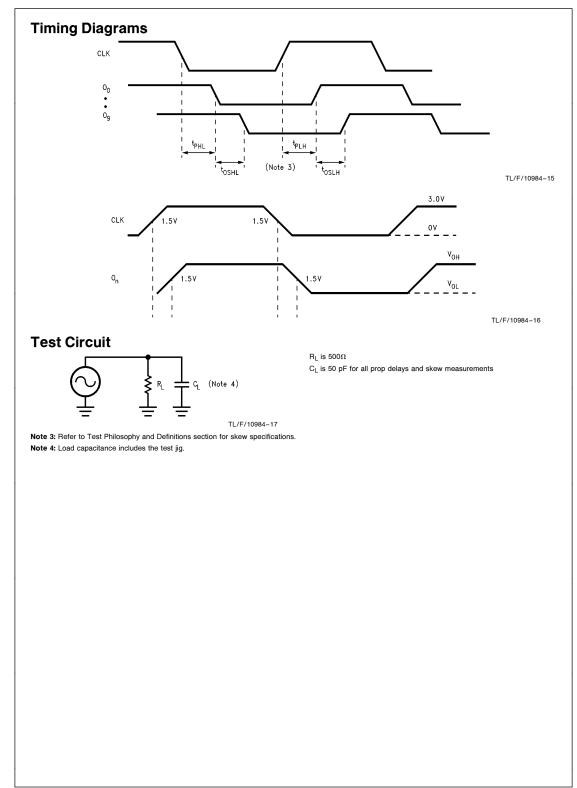
## **DC Electrical Characteristics**

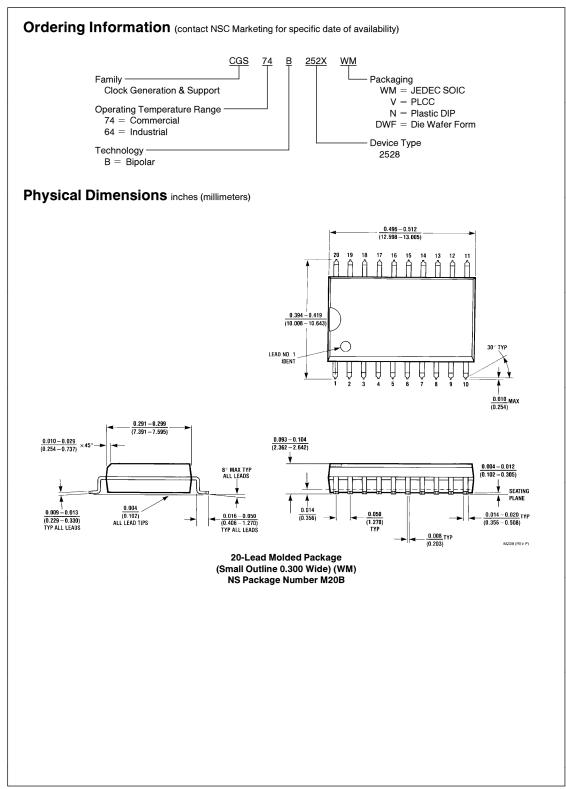
Over recommended operating conditions unless specified otherwise. All typical values are measured at  $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ .

Symbol	Parameter	Conditions		Min	Тур	Max	Units	
V <sub>IK</sub>	Input Clamp Voltage	$V_{CC} = 4.5 V, I_{I}$			-1.2	V		
V <sub>IH</sub>	Minimum Input High Level Voltage		2.0			v		
V <sub>IL</sub>	Maximum Input Low Level Voltage				0.8	v		
V <sub>OH</sub> High Level	High Level Output Voltage	$I_{OH} = -3 \text{ mA},$	$V_{CC} = 4.5V$	2.4			V	
		I <sub>OH</sub> = 48 mA, V	2.0			•		
V <sub>OL</sub>	Low Level Output Voltage	$V_{CC} = 4.5 V, I_C$		0.35	0.5	V		
l <sub>l</sub>	Input Current @ Max Input Voltage	$V_{CC}=5.5V, V_{IH}=7V$				0.1	mA	
IIH	High Level Input Current	$V_{CC} = 5.5V, V_{IH} = 2.7V$				20	μΑ	
۱ <sub>IL</sub>	Low Level Input Current	$V_{CC} = 5.5V, V_{IL} = 0.4V$			-0.5	-0.75	mA	
IO	Output Drive Current	$V_{CC} = 5.5V, V_O = 2.25V$		-50		-150	mA	
ICC	Supply Current	$V_{CC} = 5.5V$	Outputs High		24	35	mA	
			Outputs Low		45	65	mA	
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5V$			5		pF	

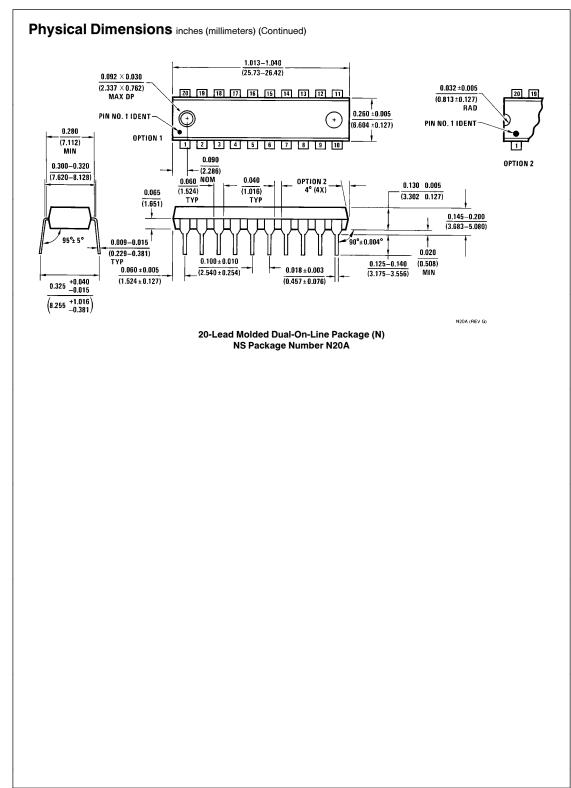
Symbol	Parameter		$V_{CC} = 4.5V \text{ to } 5.5V$ $C_L = 50 \text{ pF}$ $R_L = 500\Omega$					Units	
			Min		Тур		Max		
f <sub>MAX</sub>	Frequency Maximum				80			MHz	
t <sub>PLH</sub>	Low-to-High Propagation De CLK to O <sub>n</sub> M, N Pkg.	elay	3.0		4.5		7.0	ns	
	Low-to-High Propagation Delay CLK to O <sub>n</sub> V Pkg.		2.5		4.5		6.5		
t <sub>PHL</sub>	High-to-Low Propagation De CLK to O <sub>n</sub> M, N Pkg.	3.		4.5			7.0	ns	
	High-to-Low Propagation De CLK to O <sub>n</sub> V Pkg.				4.5		6.5	115	
Symbol	Parameter			Min	al values are measured at $V_{CC} = 5V$ $V_{CC} = 4.5V \text{ to } 5.5V$ $C_L = 50 \text{ pF}$ $R_L = 500\Omega$ Min Typ Max		Ur		
toshl	Maximum Skew Common Edge Output-to-Output Variation (Note 1)	Package N M V (Note 2)				<u>P</u>	700 450 450 550	p	
toslh	Maximum Skew Common Edge Output-to-Output Variation (Note 1)	N M V (Note 2)					700 450 450 550	p	
t <sub>PS</sub>	Maximum Skew Pin (Signal) Transition Variation	N M V					750 750 850	p	
t <sub>rise</sub> , t <sub>fall</sub>	Rise/Fall Time (from 0.8V/2.0V to 2.0V/0.8V)	CGS74 CGS64			-		1.5 1.75	n	
	d t <sub>OSLH</sub> characterized and guaranteed by design d at 66 MHz. Parameter guaranteed by design.	i≌ i wn2.							

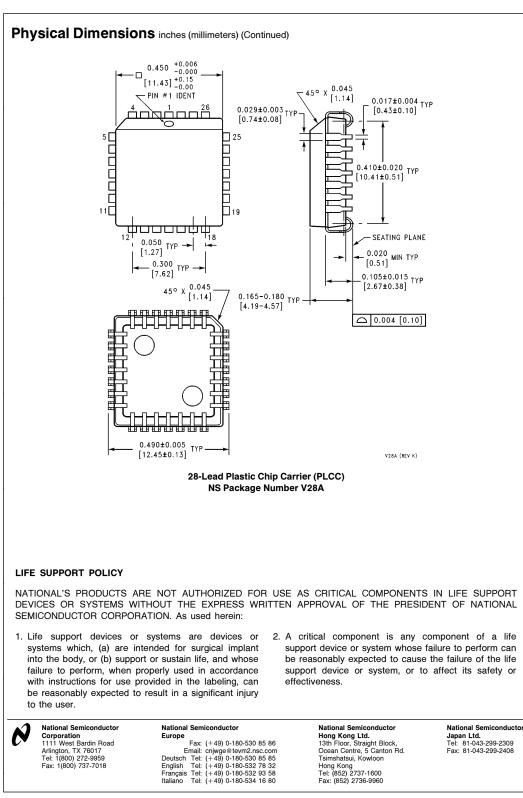
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